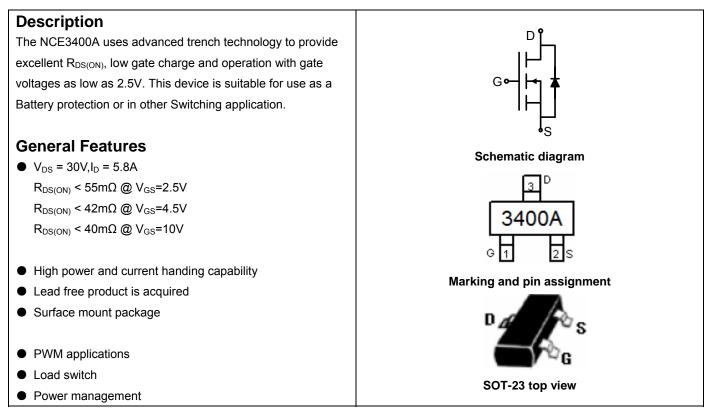




# NCE N-Channel Enhancement Mode Power MOSFET



### **Package Marking and Ordering Information**

	<u> </u>	V			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3400A	NCE3400A	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings (T<sub>A</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I <sub>D</sub>	5.8	A
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	30	A
Maximum Power Dissipation	PD	1.4	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	89	°C <b>/W</b>
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#### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	-	1	μA



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Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±12V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	0.7	0.9	1.4	V
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4A	-	41	55	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	28	42	mΩ
		V <sub>GS</sub> =10V, I <sub>D</sub> =5.8A	-	24	40	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	10	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	(-15)()(-0)(	-	825	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V, F=1.0MHz	-	100	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F = 1.00012	-	78	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	3.3	-	nS
Turn-on Rise Time	Rise Time $t_r$ $V_{DD}$ =15V, RL=2.7 $\Omega$	$V_{DD}$ =15V, R <sub>L</sub> =2.7 $\Omega$	-	4.8	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =10V, $R_{GEN}$ =3 $\Omega$	-	26	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg		-	10	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =15V,I <sub>D</sub> =5.8A, V <sub>GS</sub> =4.5V	-	1.6	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> -4.3V	-	3.1	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =5.8A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	5.8	А

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, t  $\leq$  10 sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



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## **Typical Electrical and Thermal Characteristics**

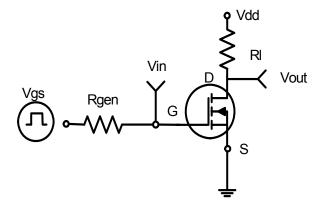
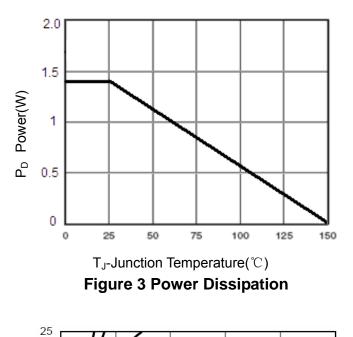
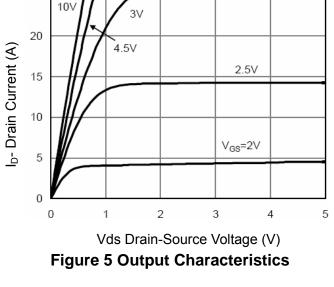


Figure 1:Switching Test Circuit





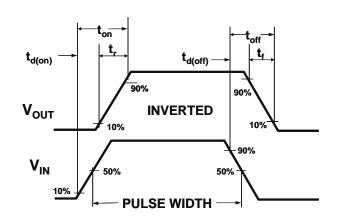
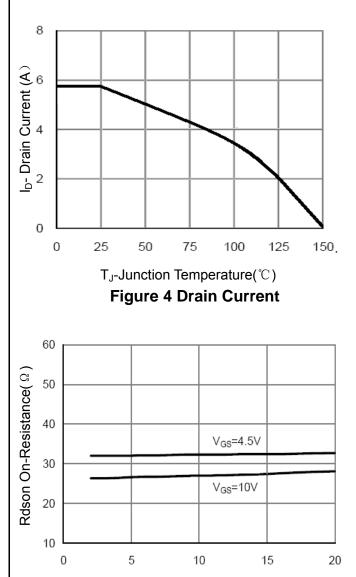


Figure 2:Switching Waveforms



I<sub>D</sub>- Drain Current (A) Figure 6 Drain-Source On-Resistance



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**Pb Free Product** 

V<sub>GS</sub>=4.5V

75

100

Ciss

15

25°C

0.6

0.8

1.0

20

25

30

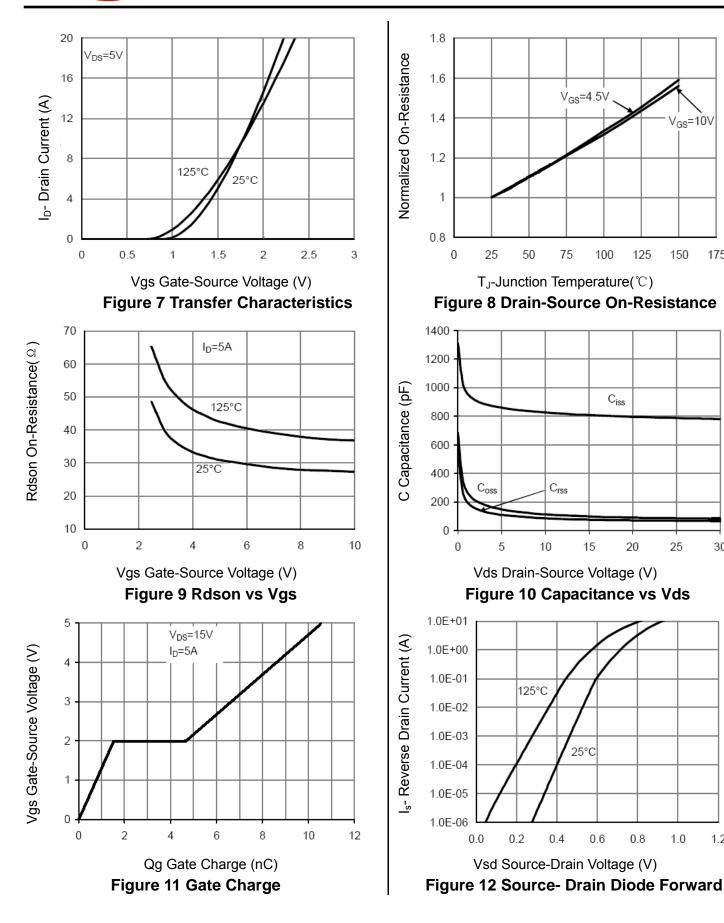
125

150

175

**NCE3400A** 

V<sub>GS</sub>=10∨



1.2





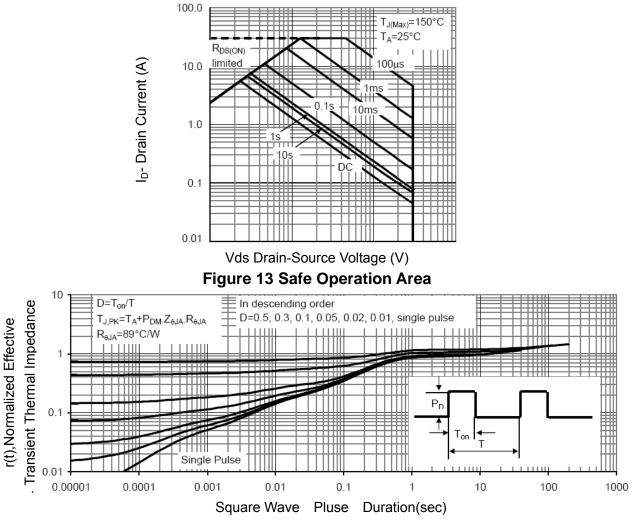


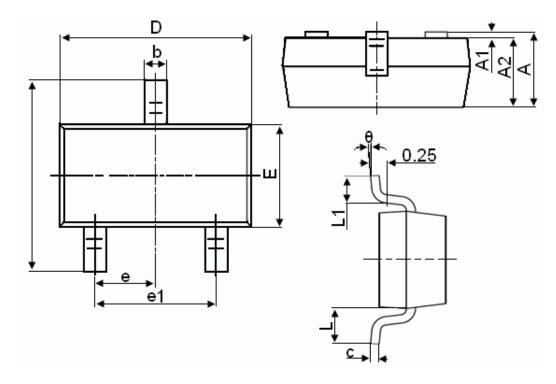
Figure 14 Normalized Maximum Transient Thermal Impedance



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# **SOT-23 Package Information**



Symbol		Dimensions in Millimeters	
Symbol	MIN.	MAX.	
A	0.900	1.150	
A1	0.000	0.100	
A2	0.900	1.050	
b	0.300	0.500	
с	0.080	0.150	
D	2.800	3.000	
E	1.200	1.400	
E1	2.250	2.550	
е	0.950TYP		
e1	1.800	2.000	
L 0.550REF		0.550REF	
L1	0.300	0.500	
θ	0°	8°	

#### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance  $\pm 0.10$ mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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